TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC74LVX74F,TC74LVX74FN,TC74LVX74FT

Dual D-Type Flip-Flop with Preset and Clear

The TC74LVX74F/ FN/ FT is a high-speed CMOS D-flip flop fabricated with silicon gate CMOS technology. Designed for use in 3-V systems, it achieves high-speed operation while maintaining the CMOS low power dissipation.

This device is suitable for low-voltage and battery operated systems.

The signal level applied to the D input is transferred to Q output during the positive going transition of the CK pulse.

 $\overline{\text{CLR}}$ and $\overline{\text{PR}}$ are independent of the CK and are accomplished by setting the appropriate input low.

An input protection circuit ensures that 0 to 5.5V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5V to 3V systems and two supply systems such as battery back up. This circuit prevents device destruction due to mismatched supply and input voltages.

Features

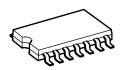
- High-speed: $f_{max} = 145 \text{ MHz}$ (typ.) (V_{CC} = 3.3 V)
- Low power dissipation: $I_{CC} = 2 \mu A \text{ (max) (Ta} = 25 ^{\circ}\text{C)}$
- Input voltage level: $V_{IL} = 0.8 \text{ V (max) (V}_{CC} = 3 \text{ V)}$

$$V_{IH} = 2.0 \text{ V (min) (V}_{CC} = 3 \text{ V)}$$

- Power-down protection provided on all inputs
- Balanced propagation delays: tpLH ~ tpHL
- Pin and function compatible with 74HC74

Note: xxxFN (JEDEC SOP) is not available in Japan.





SOP14-P-300-1.27

TC74LVX74FN

TC74LVX74F



SOL14-P-150-1.27

TC74LVX74FT



TSSOP14-P-0044-0.65A

Weight

 SOP14-P-300-1.27A
 : 0.18 g (typ.)

 SOP14-P-300-1.27
 : 0.18 g (typ.)

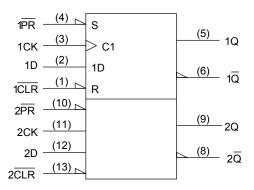
 SOL14-P-150-1.27
 : 0.12 g (typ.)

 TSSOP14-P-0044-0.65A
 : 0.06 g (typ.)

Pin Assignment (top view)

1CLR V_{CC} $2\overline{\text{CLR}}$ 1D CK Q D Q 1CK 2D 3 1PR 2CK 2PR 1Q D 1Q 2Q Q GND $2\overline{Q}$

IEC Logic Symbol



Truth Table

	uts		Out	puts	Function		
CLR	PR	D	CK	Q	Q	T diletion	
L	Н	Х	Х	L	Н	Clear	
Н	L	Х	Х	Н	L	Preset	
L	L	Х	Х	Н	Н	_	
Н	Н	L	\Box	L	Н	_	
Н	Н	Н		Н	Ĺ	_	
Н	Н	Х	—	Qn	Qn	No change	

X: Don't care

Absolute Maximum Ratings (Note)

Characteristics	Symbol	Rating	Unit
Supply voltage range	V _{CC}	-0.5 to 7.0	V
DC input voltage	V _{IN}	-0.5 to 7.0	٧
DC output voltage	V _{OUT}	-0.5 to $V_{CC} + 0.5$	٧
Input diode current	I _{IK}	-20	mA
Output diode current	I _{OK}	±20	mA
DC output current	lout	±25	mA
DC V _{CC} /ground current	Icc	±50	mA
Power dissipation	P _D	180	mW
Storage temperature	T _{stg}	-65 to 150	°C

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

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Recommended Operating Conditions (Note)

Characteristics	Symbol	Rating	Unit
Supply voltage	V _{CC}	2.0 to 3.6	V
Input voltage	V _{IN}	0 to 5.5	V
Output voltage	V _{OUT}	0 to V _{CC}	V
Operating temperature	T _{opr}	-40 to 85	°C
Input rise and fall time	dt/dv	0 to 100	ns/V

Note: The recommended operating conditions are required to ensure the normal operation of the device. Unused inputs must be tied to either VCC or GND.

Electrical Characteristics

DC Characteristics

Characteristics		Sym-	Sym- bol Test Condition		Ta = 25°C			Ta = -40 to 85°C		Unit	
		DOI			V _{CC} (V)	Min	Тур.	Max	Min	Max	
Input voltage					2.0	1.5	_	_	1.5	_	
	H-level	V_{IH}	_		3.0	2.0	_	_	2.0	_	. v
					3.6	2.4	_	_	2.4	_	
	L-level	V _{IL}	_		2.0	_	_	0.5	_	0.5	
					3.0	_	_	0.8	_	0.8	
					3.6	_	_	0.8	_	0.8	
	H-level	V _{OH}	V _{IN} = V _{IH} or V _{IL}	$I_{OH} = -50 \mu A$	2.0	1.9	2.0	_	1.9	_	
				I _{OH} = -50 μA	3.0	2.9	3.0	_	2.9	_	
Output voltage				I _{OH} = -4 mA	3.0	2.58	_	_	2.48	_	V
Output voltage			V _{IN} = V _{IH} or V _{IL}	$I_{OL} = 50 \mu A$	2.0	_	0	0.1	_	0.1	V
	L-level	V _{OL}		I _{OL} = 50 μA	3.0	_	0	0.1	_	0.1	
				I _{OL} = 4 mA	3.0	_	_	0.36	_	0.44	
Input leakage currer	Input leakage current		V _{IN} = 5.5 V or GND		3.6		_	±0.1	_	±1.0	μА
Quiescent supply cu	ırrent	Icc	$V_{IN} = V_{CC}$	or GND	3.6		_	2.0	_	20.0	μА

Timing Requirements (input: $t_r = t_f = 3 \text{ ns}$)

Characteristics	Symbol	Test Condition		Ta = 25°C	Ta = -40 to 85°C	Unit	
			V _{CC} (V)	Limit	Limit		
Minimum pulse width	t _{W (L)}		2.7	8.5	10.0	ns	
(CK)	t _{W (H)}	_	3.3 ± 0.3	6.0	7.0		
Minimum pulse width			2.7	8.5	10.0	ns	
(CLR, PR)	t _{W (L)}	_	3.3 ± 0.3	6.0	7.0		
Minimum act up time			2.7	8.0	9.5	- ns	
Minimum set-up time	t _s	_	3.3 ± 0.3	5.5	6.5		
Minimum hold time			2.7	0.5	0.5	- ns	
Minimum hold time	t _h	_	3.3 ± 0.3	0.5	0.5		
Minimum removal time	4		2.7	6.5	7.5		
(CLR, PR)	t _{rem}	_	3.3 ± 0.3	5.0	5.0	ns	



AC Characteristics (input: $t_r = t_f = 3$ ns)

Characteristics	Symbol	Test Condition	est Condition		Ta = 25°C		Ta = -40 to 85°C		Unit	
			V _{CC} (V)	C _L (pF)	Min	Тур.	Max	Min	Max	
	t		2.7	15	_	7.3	15.0	1.0	18.5	
Propagation delay time	t _{pLH}		2.1	50	_	9.8	18.5	1.0	22.0	ns
(CK-Q, \overline{Q})	t		3.3 ± 0.3	15		5.7	9.7	1.0	11.5	
	t _{pHL}		3.3 ± 0.3	50		8.2	13.2	1.0	15.0	
	t _{pLH}	_	2.7	15		8.4	15.6	1.0	18.5	ns MHz
Propagation delay time				50		10.9	19.1	1.0	22.0	
$(\overline{CLR},\overline{PR}-Q,\overline{Q})$	t _{pHL}		3.3 ± 0.3	15		6.6	10.1	1.0	12.0	
				50	_	9.1	13.6	1.0	15.5	
			2.7 3.3 ± 0.3	15	55	135	_	50	_	
Maximum clock frequency	f			50	45	60	_	40	_	
Maximum clock frequency	f _{max}	_		15	95	145	_	80	_	
			3.3 ± 0.3	50	60	85	_	50	_	
Output to output skew	t _{osLH}	(Note 1)	2.7	50	_	_	1.5	_	1.5	ns
Output to output skew	t _{osHL}	(Note 1)	3.3 ± 0.3	50		_	1.5	_	1.5	113
Input capacitance	C _{IN}			(Note 2)	_	4	10	_	10	pF
Power dissipation capacitance	C_{PD}			(Note 3)		25	_		_	pF

Note 1: Parameter guaranteed by design.

 $(t_{OSLH} = |t_{pLHm} - t_{pLHn}|, t_{OSHL} = |t_{pHLm} - t_{pHLn}|)$

Note 2: Parameter guaranteed by design.

Note 3: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption.

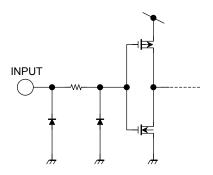
Average operating current can be obtained by the equation:

 $I_{CC \text{ (opr)}} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/2 \text{ (per F/F)}$

Noise Characteristics (Ta = 25°C, input: $t_r = t_f = 3$ ns, $C_L = 50$ pF)

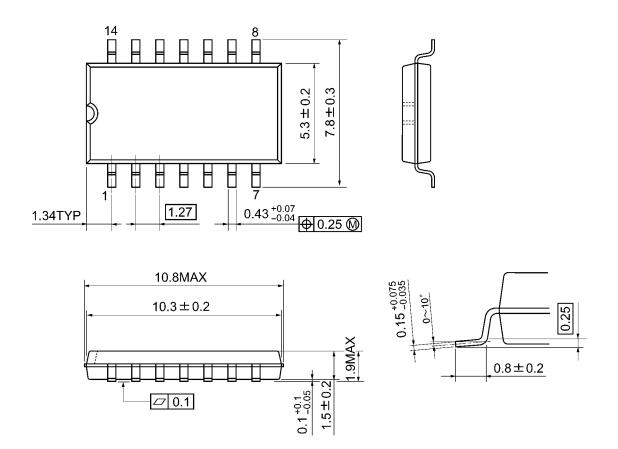
Characteristics	Symbol	Test Condition	V _{CC} (V)	Тур.	Limit	Unit
Quiet output maximum dynamic V _{OL}	V _{OLP}	_	3.3	0.3	0.5	V
Quiet output minimum dynamic V _{OL}	V _{OLV}	_	3.3	-0.3	-0.5	V
Minimum high level dynamic input voltage $V_{\mbox{\scriptsize IH}}$	V_{IHD}	_	3.3	_	2.0	V
Maximum low level dynamic input voltage V_{IL}	V _{ILD}	_	3.3		0.8	V

Input Equivalent Circuit



Package Dimensions

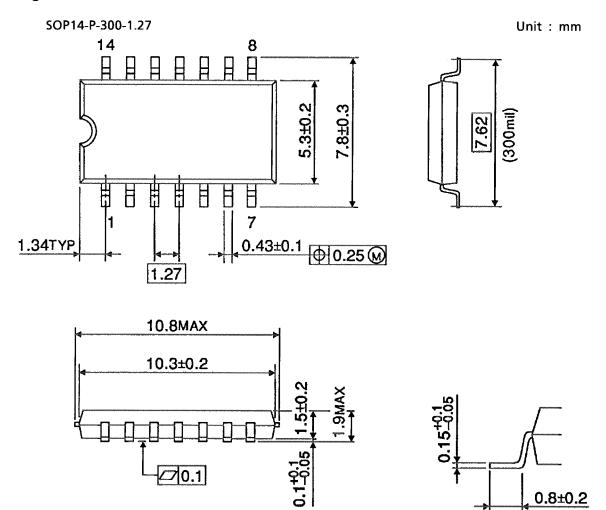
SOP14-P-300-1.27A Unit: mm



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Weight: 0.18 g (typ.)

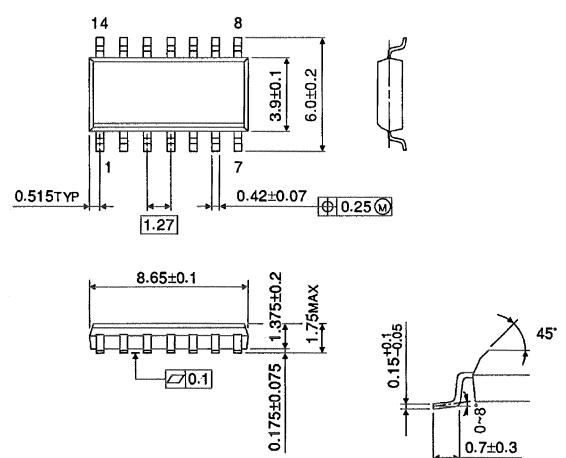
Package Dimensions



Weight: 0.18 g (typ.)

Package Dimensions (Note)

SOL14-P-150-1.27 Unit: mm



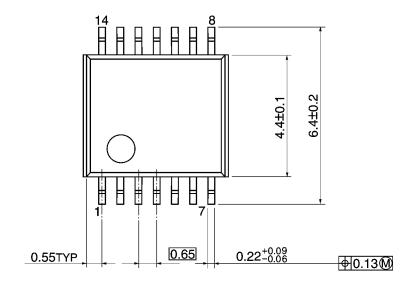
Note: This package is not available in Japan.

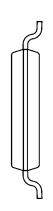
Weight: 0.12 g (typ.)

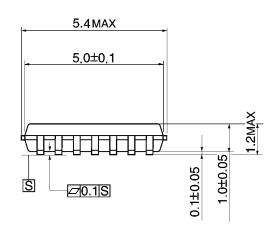
Package Dimensions

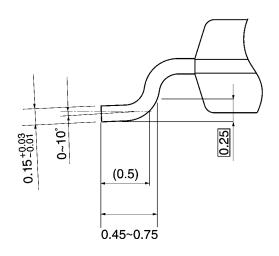
TSSOP14-P-0044-0.65A

Unit: mm









Weight: 0.06 g (typ.)

Note: Lead (Pb)-Free Packages

SOP14-P-300-1.27A SOL14-P-150-1.27 TSSOP14-P-0044-0.65A

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